

1 Amp. Surface Mount Schottky Barrier Rectifiers

<div data-bbox="188 369 268 448"></div> <div data-bbox="293 389 395 443">RoHS COMPLIANCE</div> <div data-bbox="528 378 738 448">CASE: SMB/DO-214AA</div> <div data-bbox="279 465 644 904"> <p>XX = Marking code WW = Week code Y = Year code</p> </div> <div data-bbox="504 1010 756 1043">Dimensions in mm.</div>	<div data-bbox="871 383 1054 454">Voltage 20 V to 150 V</div> <div data-bbox="1241 383 1353 454">Current 1.0 A</div> <div data-bbox="823 499 1353 824"> <ul style="list-style-type: none"> • For surface mounted application • Easy pick and place • Metal to silicon rectifier, majority carrier conduction • Low power loss, high efficiency • High current capability. low VF • High surge current capability • Plastic material used carriers Underwriters Laboratory Classification 94V-0 • Epitaxial construction • High temperature soldering: 260 °C / 10 seconds at terminals </div> <div data-bbox="823 864 1043 891">MECHANICAL DATA</div> <div data-bbox="823 902 1246 1050"> <p>Case: Molded plastic Terminals: Pure tin plated, lead free Polarity: Indicated by cathode band Packaging: 16 mm tape EIA-STD RS-481. Weight: 0.093 g.</p> </div>
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Maximum Ratings and Electrical Characteristics at 25 °C

		SK 12B	SK 13B	SK 14B	SK 15B	SK 16B	SK 19B	SK 110B	SK 115B
	Marking code	I1	I2	I3	I4	I5	I6	I7	I8
V _{RRM}	Maximum Recurrent Peak Reverse Voltage (V)	20	30	40	50	60	90	100	150
V _{RMS}	Maximum RMS Voltage (V)	14	21	28	35	42	63	70	105
V _{DC}	Maximum DC Blocking Voltage (V)	20	30	40	50	60	90	100	150
I _{F(AV)}	Maximum Average Forward Rectified Current at T _L (See graphic)	1.0 A							
I _{FSM}	8.3 ms. Peak Forward Surge Current (Jedec Method)	30 A							
T _j	Operating Temperature Range	-55°C to +125°C			-55°C to +150°C				
T _{stg}	Storage Temperature Range	-55°C to +150°C							

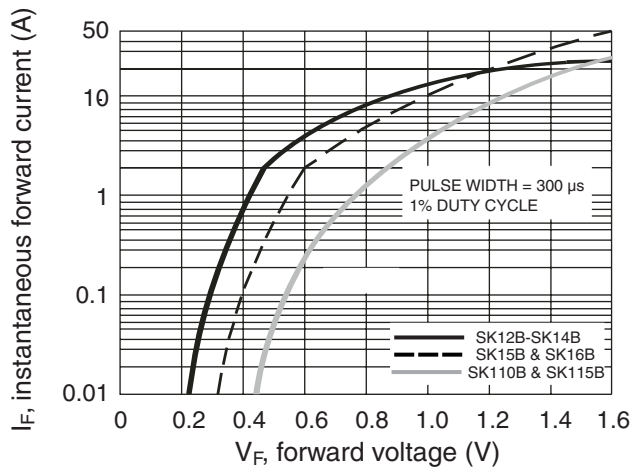
Electrical Characteristics at Tamb = 25 °C

V _F	Maximum Instantaneous Forward Voltage @ 1.0 A	0.5 V	0.75 V	0.85 V	0.95 V
I _R	Maximum DC Reverse Current (Note 1) T _A = 25 °C	0.5 mA		0.1 mA	
	at Rated DC Blocking Voltage T _A =100°C	10 mA	5.0 mA	--	
	T _A =125°C	--		2.0 mA	
C _j	Typical Junction Capacitance (Note 2)	110 pF			
R _{thj-l}	Typical Thermal Resistance (Note 3)	25 °C/W			

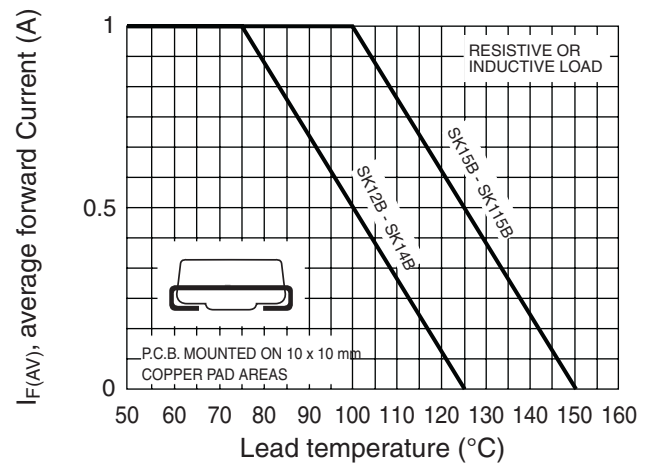
NOTES: 1. Pulse Test With PW = 300 µsec, 1% Duty Cycle
2. Measured at 1 MHz and Applied Reverse Voltage of 4.0 V D.C.
3. Measured on P.C. Board with 10mm x10mm Copper Pad Areas

Rating And Characteristic Curves

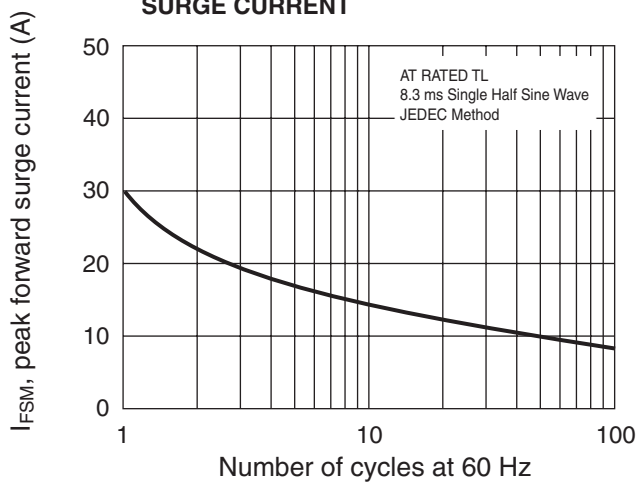
TYPICAL FORWARD CHARACTERISTIC



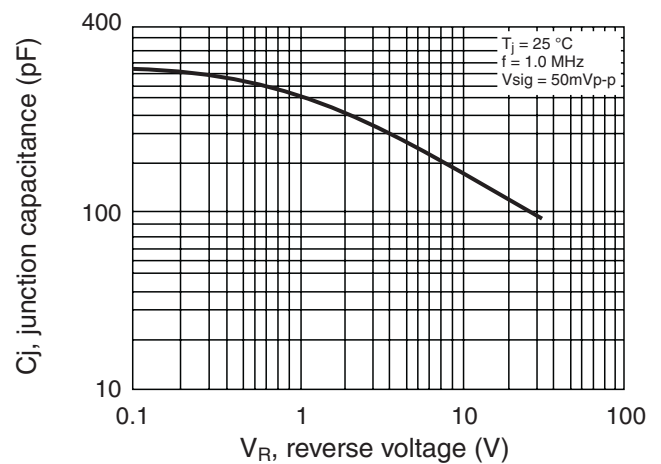
MAXIMUM FORWARD CURRENT DERATING CURVE



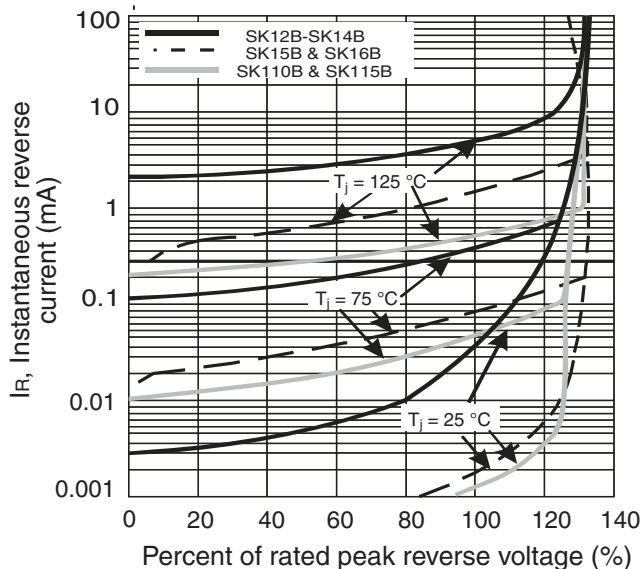
MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT



TYPICAL JUNCTION CAPACITANCE



TYPICAL REVERSE CHARACTERISTIC



TYPICAL TRANSIENT THERMAL CHARACTERISTIC

